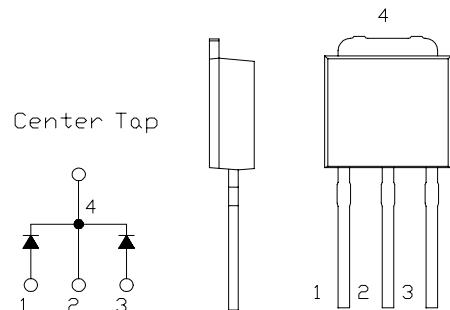


# SBD Type : EA20QC04

## OUTLINE DRAWING

### FEATURES

- \* TO-251AA Case
- \* Dual Diodes Cathode Common
- \* Low Forward Voltage drop
- \* Low Power Loss
- \* High Surge Capability
- \* 40 Volts thru 100 Volts Types Available



### Maximum Ratings

Approx Net Weight:0.35g

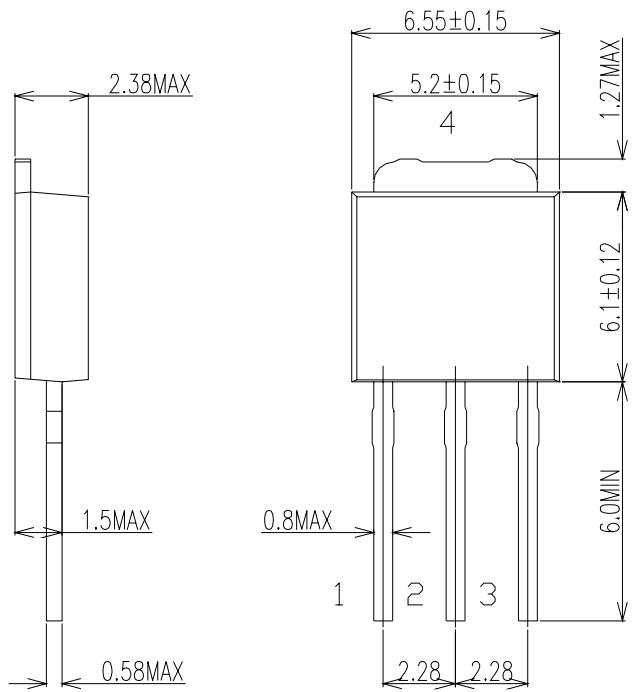
Rating		Symbol	EA20QC04				Unit						
Repetitive Peak Reverse Voltage		$V_{RRM}$	40				V						
Non-repetitive Peak Reverse Voltage		$V_{RSM}$	45				V						
Average Rectified Output Current	P.C. Board mounted *	$I_o$	1.6	Ta=31°C	50Hz Full Sine Wave Resistive Load		A						
			2	Tc=137°C									
RMS Forward Current		$I_{F(RMS)}$	2.22				A						
Surge Forward Current		$I_{FSM}$	20	50Hz Full Sine Wave, 1cycle, Non-repetitive			A						
Operating JunctionTemperature Range		$T_{jw}$	- 40 to + 150				°C						
Storage Temperature Range		$T_{stg}$	- 40 to + 150				°C						

### Electrical • Thermal Characteristics

Characteristics		Symbol	Conditions		Min	Typ	Max	Unit
Peak Reverse Current		$I_{RM}$	$T_j=25^\circ C, V_{RM}=V_{RRM}$ per Arm		-	-	1.0	mA
Peak Forward Voltage		$V_{FM}$	$T_j=25^\circ C, I_{FM}= 1 A$ per Arm		-	-	0.55	V
Thermal Resistance	Junction to Ambient	$R_{th(j-a)}$	P.C. Board mounted *		-	-	80	°C/W
	Junction to Case	$R_{th(j-c)}$		-	-	-	6	°C/W

\* Print Land = 20x20 mm

## EA20QC04 OUTLINE DRAWING (Dimensions in mm)



Center Tap

